

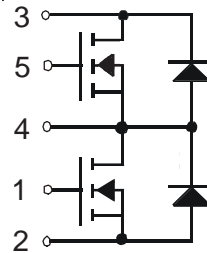
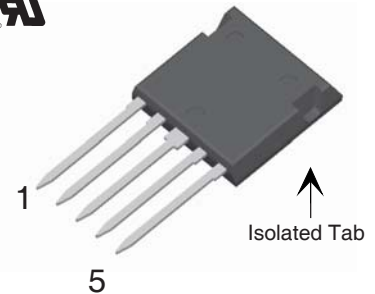
**Trench Gate HiperFET  
N-Channel Power MOSFET**
**FMM60-02TF**

$$V_{DSS} = 200V$$

$$I_{D25} = 33A$$

$$R_{DS(on)} \leq 40m\Omega$$

$$t_{rr(typ)} = 82ns$$

**Phase Leg Topology**

**ISOPLUS i4-Pak™**


Symbol	Test Conditions	Maximum Ratings	
$T_J$		-55 ... +150	°C
$T_{JM}$		150	°C
$T_{stg}$		-55 ... +150	°C
$V_{ISOLD}$	50/60Hz, RMS, t = 1min, leads-to-tab	2500	~V
$T_L$	1.6mm (0.062 in.) from case for 10s	300	°C
$T_{SOLD}$	Plastic body for 10s	260	°C
$F_C$	Mounting force	20..120 / 4.5..27	N/lb.

Symbol	Test Conditions	Maximum Ratings	
$V_{DSS}$	$T_J = 25^\circ C$ to $150^\circ C$	200	V
$V_{DGR}$	$T_J = 25^\circ C$ to $150^\circ C$ , $R_{GS} = 1M\Omega$	200	V
$V_{GSM}$	Transient	$\pm 30$	V
$I_{D25}$	$T_C = 25^\circ C$	33	A
$I_{DM}$	$T_C = 25^\circ C$ , pulse width limited by $T_{JM}$	150	A
$I_A$	$T_C = 25^\circ C$	5	A
$E_{AS}$	$T_C = 25^\circ C$	1	J
$dV/dt$	$I_S \leq I_{DM}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ C$	10	V/ns
$P_D$	$T_C = 25^\circ C$	125	W

Symbol	Test Conditions	Characteristic Values		
		Min.	Typ.	Max.
$C_p$	Coupling capacitance between shorted pins and mounting tab in the case		40	pF
$d_S, d_A$	pin - pin	1.7		mm
$d_S, d_A$	pin - backside metal	5.5		mm
<b>Weight</b>			9	g

**Features**

- Silicon chip on Direct-Copper Bond (DCB) substrate
  - UL recognized package
  - Isolated mounting surface
  - 2500V electrical isolation
- Avalanche rated
- Low  $Q_g$
- Low Drain-to-Tab capacitance
- Low package inductance

**Advantages**

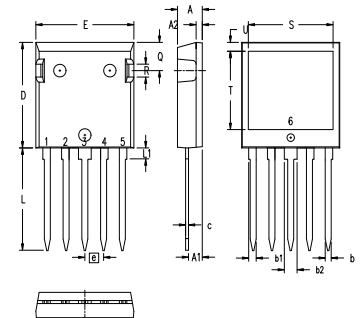
- Low gate drive requirement
- High power density
- Fast intrinsic rectifier
- Low drain to ground capacitance
- Fast switching

**Applications**

- DC and AC motor drives
- UPS, solar and wind power inverters
- Synchronous rectifiers
- Multi-phase DC to DC converters
- Industrial battery chargers
- Switching power supplies

Symbol	Test Conditions <sup>2</sup> (T <sub>J</sub> = 25°C unless otherwise specified)	Characteristic Values		
		Min.	Typ.	Max.
<b>BV<sub>DSS</sub></b>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	200		V
<b>V<sub>GS(th)</sub></b>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA	2.5		4.5 V
<b>I<sub>GSS</sub></b>	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0V			± 200 nA
<b>I<sub>DSS</sub></b>	V <sub>DS</sub> = V <sub>DSS</sub> V <sub>GS</sub> = 0V T <sub>J</sub> = 125°C			5 μA 250 μA
<b>R<sub>DS(on)</sub></b>	V <sub>GS</sub> = 10V, I <sub>D</sub> = 30A, Note 1		32	40 mΩ
<b>g<sub>fs</sub></b>	V <sub>DS</sub> = 10V, I <sub>D</sub> = 60A, Note 1	40	62	S
<b>C<sub>iss</sub></b>	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 25 V, f = 1 MHz		3700	pF
<b>C<sub>oss</sub></b>			520	pF
<b>C<sub>rss</sub></b>			37	pF
<b>t<sub>d(on)</sub></b>	<b>Resistive Switching Times</b> V <sub>GS</sub> = 10V, V <sub>DS</sub> = 0.5 • V <sub>DSS</sub> , I <sub>D</sub> = 30A R <sub>G</sub> = 5Ω (External)		39	ns
<b>t<sub>r</sub></b>			46	ns
<b>t<sub>d(off)</sub></b>			75	ns
<b>t<sub>f</sub></b>			42	ns
<b>Q<sub>g(on)</sub></b>	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 0.5 • V <sub>DSS</sub> , I <sub>D</sub> = 30A		90	nC
<b>Q<sub>gs</sub></b>			33	nC
<b>Q<sub>gd</sub></b>			21	nC
<b>R<sub>thJC</sub></b>				1.0 °C/W
<b>R<sub>thCS</sub></b>		0.15		°C/W

### ISOPLUS i4-Pak™ Outline



NOTE: Bottom heatsink meets 3000 Volts AC 1 sec isolation to the other pins.

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.190	.205	4.83	5.21
A1	.102	.118	2.59	3.00
A2	.046	.085	1.17	2.16
b	.045	.055	1.14	1.40
b1	.058	.068	1.47	1.73
b2	.100	.110	2.54	2.79
C	.020	.029	0.51	0.74
D	.819	.840	20.80	21.34
E	.770	.799	19.56	20.29
e	.150 BSC		3.81 BSC	
L	.780	.840	19.81	21.34
L1	.083	.102	2.11	2.59
Q	.210	.244	5.33	6.20
R	.100	.180	2.54	4.57
S	.660	.690	16.76	17.53
T	.590	.620	14.99	15.75
U	.065	.080	1.65	2.03

Ref: IXYS CO 0077 R0

### Source-Drain Diode

Symbol	Test Conditions <sup>3</sup>	Characteristic Values		
		Min.	Typ.	Max.
<b>I<sub>S</sub></b>	V <sub>GS</sub> = 0V			33 A
<b>I<sub>SM</sub></b>	Repetitive, pulse width limited by T <sub>JM</sub>			150 A
<b>V<sub>SD</sub></b>	I <sub>F</sub> = 60A, V <sub>GS</sub> = 0V, Note 1			1.5 V
<b>t<sub>rr</sub></b>	I <sub>F</sub> = 25A, -di/dt = 100A/μs V <sub>R</sub> = 100V, V <sub>GS</sub> = 0V		82	ns
<b>I<sub>RM</sub></b>			15.3	A
<b>Q<sub>RM</sub></b>			0.63	μC

Note 1: Pulse test, t ≤ 300μs, duty cycle, d ≤ 2 %.

### ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated objective result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

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IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:	4,835,592	4,931,844	5,049,961	5,237,481	6,162,665	6,404,065 B1	6,683,344	6,727,585	7,005,734 B2	7,157,338B2
	4,850,072	5,017,508	5,063,307	5,381,025	6,259,123 B1	6,534,343	6,710,405 B2	6,759,692	7,063,975 B2	
	4,881,106	5,034,796	5,187,117	5,486,715	6,306,728 B1	6,583,505	6,710,463	6,771,478 B2	7,071,537	

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